

INCHANGE SEMICONDUCTOR

isc Silicon NPN Power Transistor

2SD1506

DESCRIPTION

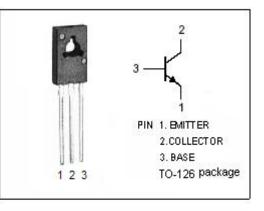
- Low Collector Saturation Voltage
 : V_{CE(sat)}= 1.0V(Max)@I_C= 2A
- Wide Area of Safe Operation
- Complement to Type 2SB1065
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

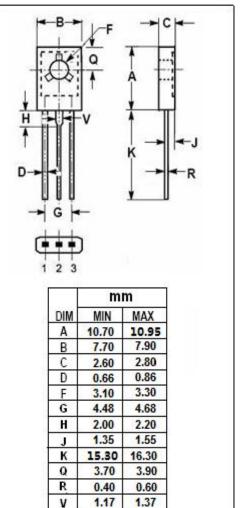
APPLICATIONS

• Designed for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V _{CBO}	Collector-Base Voltage	60	V			
V _{CEO}	Collector-Emitter Voltage	50	V			
V _{EBO}	Emitter-Base Voltage	5	V			
lc	Collector Current-Continuous	3	A			
Ісм	Collector Current-Peak	4.5	A			
Pc	Total Power Dissipation @ T₂=25℃	1.2	W			
	Total Power Dissipation @ T _C =25℃	10				
TJ	Junction Temperature	150	°C			
T _{stg}	Storage Temperature Range	-55~150	°C			

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)







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ELECTRICAL CHARACTERISTICS

$T_{\text{c}}\text{=}25\,^{\circ}\!\!^{\circ}\!\!^{\circ}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _c = 1mA; I _B = 0	50			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 50 μ A; I _E = 0	60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 50 μ A; I _C = 0	5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	Ic= 2A; I _B = 0.2A			1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 2A; I _B = 0.2A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 40V; I _E = 0			1.0	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0			1.0	μA
h _{FE}	DC Current Gain	I _C = 0.5A; V _{CE} = 3V	56		390	
f _T	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 5V		90		MHz
Сов	Output Capacitance	I _E =0; V _{CB} = 10V; f= 1MHz		40		pF

• h_{FE} Classifications

Ν	Р	Q	R
56-120	82-180	120-270	180-390

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